

Designing a flyback DC/DC converter

Video 3

Flyback converter design procedure I

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Outline of video series

1. Guidelines for topology selection
2. Fundamentals of flyback converters
3. Flyback converter design procedure I
4. Flyback converter design procedure II
5. Flyback transformer basics
6. Practical issues experienced with flyback converters

Flyback design procedure

- Demonstrated with the LM5155
- Summary of design steps
 - Identify the application's specs: V_{IN} range, V_{OUT} , max P_O , ripple voltages, switching frequency, etc.
 - Select a controller IC
 - Determine transformer specs and max duty cycle: turns ratio, primary inductance, peak current
 - Calculate key parameters: I_{pk} , V_{DSmax} , I_{rms} , PIV
 - Select MOSFET, current sense resistor, rectifier diode, input and output capacitors
 - Determine the loop compensation
 - Non-isolated
 - PSR
 - Isolated
 - Other external components
 - PCB design
 - Test and fine tune

Flyback design procedure – example specs

Table 1. Design Parameters

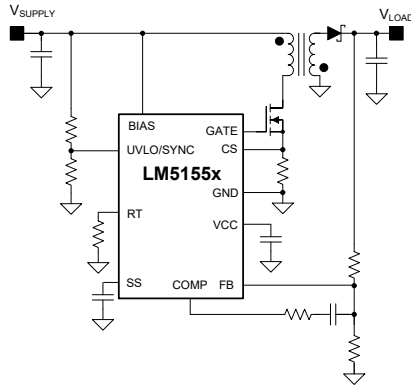
Parameter	
V_{SUPPLY}	18V to 36V
V_{LOAD}	5V
I_{LOAD}	4A
V_{AUX}	10V
I_{AUX}	20mA
$P_{\text{OUT_total}}$	20.2W
f_{SW}	250kHz

Applications with additional output rails will be covered in another video.

Different flyback types

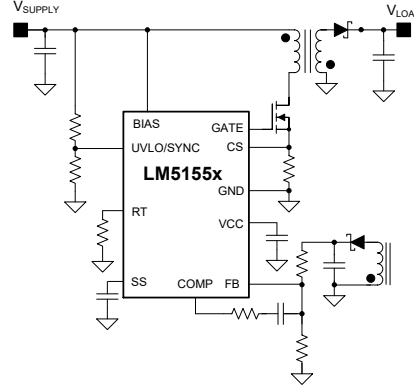
examples based on LM5155x(-Q1)

Non-Isolated Flyback



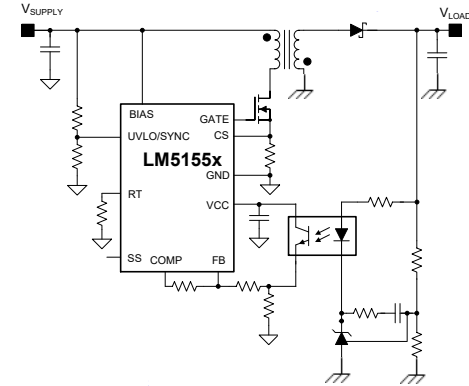
- Simplest
- Tight regulation (1~2%)
- Only non-isolated V_{OUT}

PSR Flyback



- Simpler for isolated V_{OUT}
- No optocoupler needed
- V_{OUT} cross regulated, 5~10%

Isolated Flyback



- Tight regulation for isolated V_{OUT} (1~2%)
- Complex, requiring optocoupler

IC selection

- Converter vs controller
 - V_{INmax} disqualifies the TPS55340 and LM5157x due to limited FET voltage
 - Max power disqualifies the LM500x family due to FET peak current limit
 - LM5155x/56x are a reasonable choice
 - Newer device, better performance
 - ***We recommend using the LM5155x/56x for new designs***
 - LM5156x has optional **spread spectrum** option
 - LM5155x and LM5156x are drop in substitutes
 - Either LM515x or LM515x1 can be used: they have almost the same performance
 - LM5155/56 do not have hiccup OCP
 - Under OCP, it will continue switching with reduced duty cycle
 - LM51551/561 have hiccup OCP
 - Under OCP, it will run in hiccup mode
 - ON for 64 consecutive cycles, followed by OFF for 32k cycles, to prevent overheating

LM5155x (-Q1)

2.2MHz Wide VIN Non-synchronous Boost/SEPIC/Flyback Controller

Features

- AEC-Q100 grade 1 qualified ($T_A = -40^{\circ}\text{C}$ to 125°C , $T_J = -40^{\circ}\text{C}$ to 150°C)
- Wide input range : **3.5V~ 45V**
(2.97V ~ 16V when $\text{BIAS}=\text{VCC}$, 1.5V~45V when $\text{BIAS}\geq 2.97\text{V}$)
- Programmable frequency 100kHz to **2.2MHz** with clock synchronization
- Shutdown $I_Q \leq 5\mu\text{A}$
- Non-switching $I_Q \leq 450\mu\text{A}$
- 1.5A peak gate driver
- 100mV current limit threshold with optional hiccup mode protection
- 1.0V +/-1% reference
- Adjustable slope compensation
- Programmable line UVLO
- Adjustable soft-start
- PGOOD indicator
- OVP protection
- Thermal shutdown
- 12pin-WSON package (3mmx2mm); -Q1 has Wettable Flanks

Applications

- General purpose Boost / Sepic
- Battery powered application
- Automotive LED headlights
- Industrial Flyback power supply/ Primary side controlled flyback

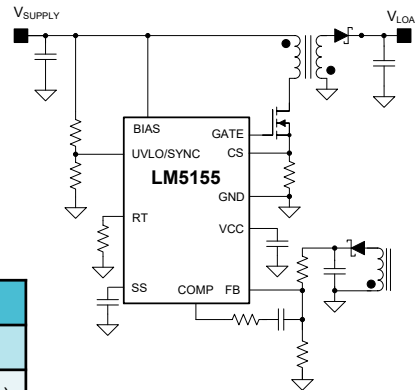
Benefits

- Boost/SEPIC/Flyback(Non-isolated/isolated) configurable
- Wide VIN for a variety of power rails including 1-cell battery
- Switching frequency out of AM band
- Small solution size at 2.2MHz
- Low shutdown I_Q reduces battery drain in battery-powered application
- Low current limit threshold minimizes power loss
- Optional hiccup mode for sustained overload / short-circuit protection
- Allows high step-up ratio using SYNC



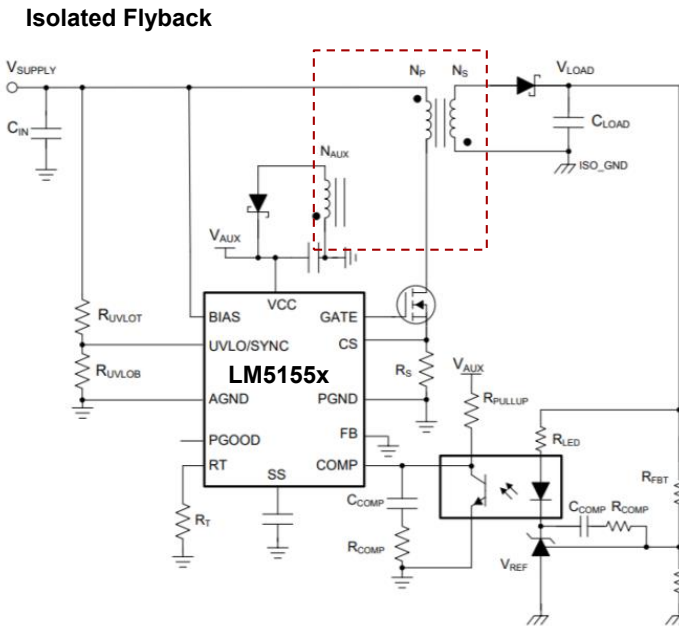
Hiccup mode protection	
Disabled	Enabled
LM5155 (-Q1)	LM51551 (-Q1)

PSR Flyback



IC supply through bias winding

- Adding the bias winding to off-load the internal LDO and reduce IC power dissipation
 - Also applies to PSR and non-isolated designs



Switching frequency

- The targeted flyback is a hard switching circuit
 - faster switching causes greater switching losses
- 100 kHz to 400 kHz are commonly chosen frequencies
- 250 kHz is a good trade-off between solution size and efficiency

$$R_T = \frac{2.21 \times 10^{10}}{f_{sw}} - 955 = \frac{2.21 \times 10^{10}}{250\text{kHz}} - 955 = 87.44\text{k}\Omega$$

A standard value of 86.6k Ω is chosen for R_T .

Determine Transformer – $N_S : N_P$

- Transformer turns ratio

$$D = \frac{\frac{N_P}{N_S} \cdot V_{LOAD}}{V_{SUPPLY} + \frac{N_P}{N_S} \cdot V_{LOAD}}$$

This example targets a duty cycle close to 0.4.

Yes, you can use a different number as long as it is smaller than IC max duty. Try to avoid extreme values.

This is an iteration process until you find a proper value.

$$N_{S_calc} = \frac{(V_{LOAD}) \cdot (1 - D_{MAX}) \cdot N_P}{V_{SUPPLY_min} \cdot D_{MAX}} = \frac{(5V) \cdot (1 - 0.4) \cdot 1}{18V \cdot 0.4} = 0.417$$

Choose an easy ratio of two integers: $N_S : N_P = 0.5 : 1$

Yes, you can choose $N_S : N_P = 0.4 : 1$ or other close number for the ratio of two integers. When designing for multiple rails, you need to get to the nearest integer ratios between all the windings.

Determine Transformer – D_{MAX} , N_{AUX}

Now: $N_S : N_P = 0.5$

$$D_{MAX} = \frac{\frac{N_P}{N_S} \cdot V_{LOAD}}{V_{SUPPLY_min} + \frac{N_P}{N_S} \cdot V_{LOAD}} = \frac{\frac{1}{0.5} \cdot 5V}{18V + \frac{1}{0.5} \cdot 5V} = 0.357 \quad D_{MIN} = \frac{\frac{1}{0.5} \cdot 5V}{36V + \frac{1}{0.5} \cdot 5V} = 0.217$$

$$N_{AUX_calc} = N_S \cdot \frac{V_{AUX}}{V_{LOAD}} = 0.5 \cdot \frac{10V}{5V} = 1$$

Transformer turns ratio: $N_P : N_S : N_{AUX} = 1 : 0.5 : 1 = 2 : 1 : 2$

If you choose $N_S : N_P = 0.4 : 1$ in previous step, you will get $N_{AUX} = 0.8$, or $N_P : N_S : N_{AUX} = 1 : 0.4 : 0.8$.
Then, you have less options in designing the actual transformer. See next page.

Transformer turns ratio selection

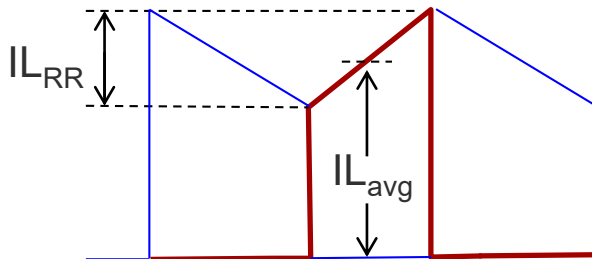
$N_P : N_S : N_{AUX}$	1 : 0.5 : 1	1 : 0.4 : 0.8
Possible design options	<ul style="list-style-type: none"> • 2 : 1 : 2 • 4 : 2 : 4 • 6 : 3 : 6 • 8 : 4 : 8 • 10 : 5 : 10 • 12 : 6 : 12 • 14 : 7 : 14 • 16 : 8 : 16 • ... 	<ul style="list-style-type: none"> • 2.5 : 1 : 2 • 5 : 2 : 4 • 7.5 : 3 : 2 • 10 : 4 : 8 • 12.5 : 5 : 10 • 15 : 6 : 12 • 17.5 : 7 : 14 • 20 : 8 : 16 • ...

Determine Transformer – L_M

- **Primary inductance L_M .** This determines the inductor ripple current for CCM.
 - Recommended ripple current to be within 30% to 70%
 - Higher ratio leads to smaller L_M

$$\frac{I_{L_{RR}}}{I_{L_{avg}}} = 60\% \text{ (selected)}$$

$$L_{M_calc} = \frac{N_P^2 \cdot V_{SUPPLY_max}^2 \cdot V_{LOAD}^2}{I_{L_{RR}} \cdot f_{SW} \cdot P_{OUT_total} \cdot (N_S \cdot V_{SUPPLY_max} + N_P \cdot |V_{LOAD}|)^2}$$
$$L_{M_calc} = \frac{1^2 \cdot 36V^2 \cdot 5V^2}{0.6 \cdot 250kHz \cdot 20.2W \cdot (0.5 \cdot 36V + 1 \cdot |5V|)^2} = 20.6\mu H$$



Choose $L_M = 21 \mu H$

Parameters dependent on transformer

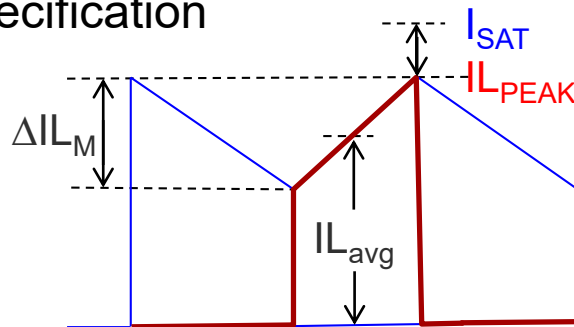
- Once the turns ratio and primary inductance are determined, the following key parameters can be calculated:
 - Primary peak current I_{PEAK} , determining R_s and the transformer I_{SAT}
 - Primary RMS current I_{RMS} , determining the conduction losses in MOSFET and transformer winding
 - V_{DS} , determining the MOSFET voltage rating
 - **PIV** (or V_R), determining the rectifier diode voltage rating

Primary peak current and saturation current

- **Peak current**, determines the transformer min I_{SAT} specification

$$\Delta I_{L_M} = \frac{V_{SUPPLY} \cdot D}{L_M \cdot f_{SW}} = \frac{18V \cdot 0.357}{21\mu H \cdot 250kHz} = 1.224A$$

$$I_{L_{PEAK}} = \frac{P_{OUT_total}}{V_{SUPPLY_min} \cdot D} + \frac{\Delta I_{L_M}}{2} = \frac{20.2W}{18V \cdot 0.357} + \frac{1.224A}{2} = 3.75A$$



Choose an I_{SAT} of 30% greater than $I_{L_{PEAK}}$ for operation margin

$I_{SAT} \geq 1.3 \times 3.75A = 4.88A$ (Wurth 750317933 is selected, $I_{SAT} = 6A$)

- **Summary** of Transformer Selection

Parameter	Value
Turns Ratio ($N_P:N_S:N_{AUX}$)	1:0.5:1 (2:1:2)
Primary winding inductance (L_M)	21 μ H
Primary winding saturation current (I_{SAT})	6A >4.88A

Video 1 to 3 Summary – Video 4 to 6 Outlook

- **We discussed**
 - **Topology selection guidelines** based on power level
 - Flyback and SEPIC topologies comparison and their suitable applications
 - **Fundamentals of flyback:** operating modes and key parameters
 - **Design procedure of the transformer** demonstrated with LM5155 example
- **We will discuss**
 - **Design procedure ongoing** demonstrated with LM5155 example, **for non-isolated, PSR and isolated applications**
 - **Flyback transformer basics**, and the need of an air gap
 - **Frequently asked questions** including multi rails, light load regulation, and high input voltage solutions, and **commonly seen mistakes**

Tools and application collaterals

Most important: E2E Forum <https://e2e.ti.com/support/>

All the following are available in the product folders on <https://www.ti.com/>

1. Flyback EVMs and user's guides
2. Excel design calculators
3. WEBENCH™ Power Designer support
4. PSpice® models
 - Transient model supports flyback
 - We are adding more average models for flyback loop simulation
5. Application notes
6. Reference designs
 - You can find many flyback reference designs at:
<https://www.ti.com/reference-designs/index.html>